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- X-rays were discovered by Wilhelm Roentgen (aka Roentgen rays) in 1895
- X-ray diffraction in crystals was discovered by Max Von Laue in 1912

Max Von Laue

- X-ray wavelength range: 0.01-10 nm
- Penetrating power depends on energy

Two types of X-rays

- Hard X-rays: high frequency & energy
- Soft X-rays: lower frequency & energy

X-rays: short wavelength electromagnetic radiations produced by deceleration of high energy electrons or by electronic transitions of electrons in the inner orbital of atoms

Principle: X-ray diffraction is based on the **constructive interference** of monochromatic X-rays and crystalline materials (samples)

- X-rays generated by cathode ray tube, filtered to produce monochromatic radiation, collimated to concentrate and directed towards sample
- Interaction of incident rays with sample produces constructive interferences when conditions satisfy Bragg's Law

X-ray diffraction (XRD)

- Non-destructive
- Analysing wide range of materials
 - Fluids
 - Metals
 - Minerals
 - Polymers
 - Plastics
 - Pharmaceuticals
 - Thin-film coating
 - Ceramics
 - Solar cells
 - Semiconductors



 Crystalline materials are characterized by orderly periodic arrangements of atoms which form a crystal lattice that extends in all directions







The (220) planes of atoms in NaCl

- The unit cell is the basic repeating unit that defines a crystal.
- Parallel planes of atoms intersecting the unit cell are used to define directions and distances in the crystal.
 - These crystallographic planes are identified by Miller indices.

Instrumentation



Diffraction on crystals

Bragg condition

Diffraction by 3D lattice of points is equivalent to a reflection of the incident beam on a family of net planes



The incident beam IC & GD scattered by 2 adjacent planes must be in phase to get constructive interference

 $FG + GH = n\lambda$ With FG = GH = d sin θ



Bragg's Law

Diffractograms of different materials



(From "Elements of X-ray Diffraction", B.D. Cullity, Addison Wesley)

Factors affecting diffraction pattern



Information in a Diffraction Pattern

- Phase Identification (Structure, using Miller indices) & quality ("residual" stress)
- Crystal Size (using Debye-Scherrer equation)
- Texture (crystalline or amorphous)



Strengths

- Powerful for sample identification
- Requires minimal sample preparation
- Relatively straightforward data interpretation

Limitations

- Homogeneous and singlephase material required for sample identification
- Access to a standard reference file of inorganic compounds is required
- For mixed materials, detection limit is » 2% of sample
- For unit cell determinations, indexing of patterns for nonisometric crystal systems is complicated
- Peak overlay may occur and worsens for high angle "reflections"

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